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FDS6692A

N-Channel PowerTrench® MOSFET

30V, 9A, 11.5mΩ

Features

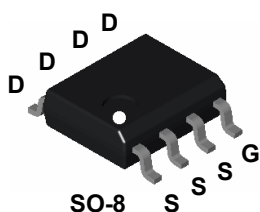
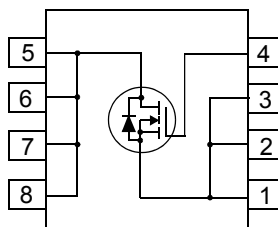
- $R_{DS(ON)} = 11.5m\Omega$, $V_{GS} = 10V$, $I_D = 9A$
- $R_{DS(ON)} = 14.5m\Omega$, $V_{GS} = 4.5V$, $I_D = 8.2A$
- High performance trench technology for extremely low $R_{DS(ON)}$
- Low gate charge
- High power and current handling capability
- RoHS Compliant

Applications

- DC/DC converters

General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $R_{DS(ON)}$ and fast switching speed.



MOSFET Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DS}	Drain to Source Voltage	30	V
V_{GS}	Gate to Source Voltage	± 20	V
I_D	Drain Current	9	A
	Continuous ($T_A = 25^\circ\text{C}$, $V_{GS} = 10\text{V}$, $R_{\theta JA} = 85^\circ\text{C/W}$)		
	Continuous ($T_A = 25^\circ\text{C}$, $V_{GS} = 4.5\text{V}$, $R_{\theta JA} = 85^\circ\text{C/W}$)	8.2	A
	Pulsed	48	A
E_{AS}	Single Pulse Avalanche Energy (Note 1)	79	mJ
P_D	Power dissipation	1.47	W
T_J, T_{STG}	Operating and Storage Temperature	-55 to 150	$^\circ\text{C}$

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient at 10 seconds (Note 3)	50	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient at 1000 seconds (Note 3)	85	$^\circ\text{C/W}$

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS6692A	FDS6692A	SO-8	330mm	12mm	2500 units

Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

B_{VDS}	Drain to Source Breakdown Voltage	$I_D = 250\mu\text{A}$, $V_{GS} = 0\text{V}$	30	-	-	V
$\frac{\Delta B_{VDS}}{\Delta T_J}$	Breakdown Voltage Temp. Coefficient	$I_D = 250\mu\text{A}$, Referenced to 25°C	-	21	-	$\text{mV}/^\circ\text{C}$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24\text{V}$ $V_{GS} = 0\text{V}$	-	-	1	μA
		$T_J = 150^\circ\text{C}$	-	-	250	
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20\text{V}$	-	-	± 100	nA

On Characteristics

$V_{GS(TH)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250\mu\text{A}$	1.2	-	2.5	V
$\frac{\Delta V_{GS(TH)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250\mu\text{A}$, Referenced to 25°C	-	-5	-	$\text{mV}/^\circ\text{C}$
$R_{DS(ON)}$	Drain to Source On Resistance	$I_D = 9\text{A}$, $V_{GS} = 10\text{V}$	-	8.2	11.5	m Ω
		$I_D = 8.2\text{A}$, $V_{GS} = 4.5\text{V}$	-	11	14.5	
		$I_D = 9\text{A}$, $V_{GS} = 10\text{V}$, $T_J = 150^\circ\text{C}$	-	13	19	

Dynamic Characteristics

C_{ISS}	Input Capacitance	$V_{DS} = 15\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$	-	1210	1610	pF
C_{OSS}	Output Capacitance		-	330	440	pF
C_{RSS}	Reverse Transfer Capacitance		-	138	210	pF
R_G	Gate Resistance	$f = 1\text{MHz}$	-	2.0	-	Ω
$Q_{g(TOT)}$	Total Gate Charge at 10V	$V_{GS} = 0\text{V}$ to 10V	-	22	29	nC
$Q_{g(5)}$	Total Gate Charge at 5V	$V_{GS} = 0\text{V}$ to 5V	-	12	16	nC
$Q_{g(TH)}$	Threshold Gate Charge	$V_{GS} = 0\text{V}$ to 1V	-	0.93	1.2	nC
Q_{gs}	Gate to Source Gate Charge	$V_{DD} = 15\text{V}$ $I_D = 9\text{A}$ $I_g = 1.0\text{mA}$	-	3	-	nC
Q_{gs2}	Gate Charge Threshold to Plateau		-	2.1	-	nC
Q_{gd}	Gate to Drain "Miller" Charge		-	4.8	-	nC
			-			

Switching Characteristics ($V_{GS} = 10V$)

t_{ON}	Turn-On Time	$V_{DD} = 15V, I_D = 9A$ $V_{GS} = 10V, R_{GS} = 6.2\Omega$	-	-	60	ns
$t_{d(ON)}$	Turn-On Delay Time		-	8	-	ns
t_r	Rise Time		-	32	-	ns
$t_{d(OFF)}$	Turn-Off Delay Time		-	33	-	ns
t_f	Fall Time		-	13	-	ns
t_{OFF}	Turn-Off Time		-	-	69	ns

Drain-Source Diode Characteristics

V_{SD}	Source to Drain Diode Voltage	$I_{SD} = 9A$	-	-	1.25	V
		$I_{SD} = 2.1A$	-	-	1.0	V
t_{rr}	Reverse Recovery Time	$I_{SD} = 9A, dl_{SD}/dt=100A/\mu s$	-	-	27	ns
Q_{RR}	Reverse Recovered Charge	$I_{SD} = 9A, dl_{SD}/dt=100A/\mu s$	-	-	17	nC

Notes:

1: Starting $T_J = 25^\circ C$, $L = 0.3mH$, $I_{AS} = 23A$, $V_{DD} = 27V$, $V_{GS} = 10V$.

2: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design.

3: $R_{\theta JA}$ is measured with 1.0 in² copper on FR-4 board

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

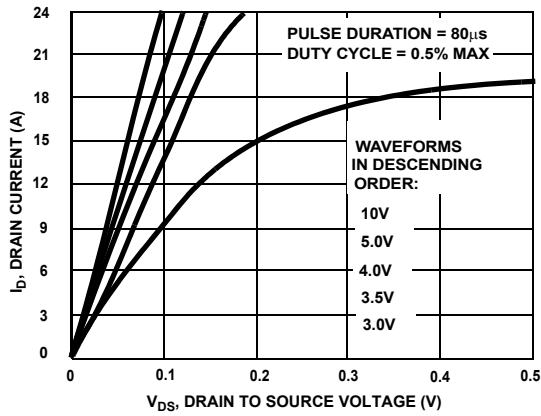


Figure 1. On Region Characteristics

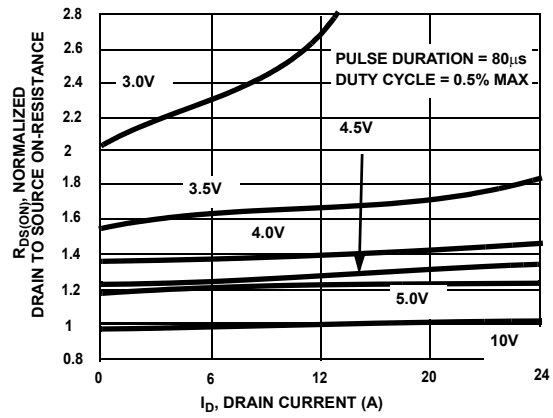


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage

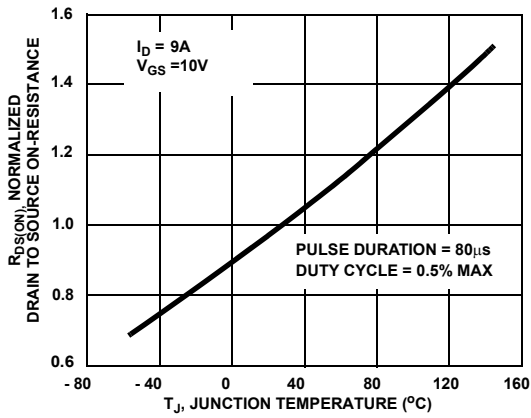


Figure 3. On Resistance Variation with Temperature

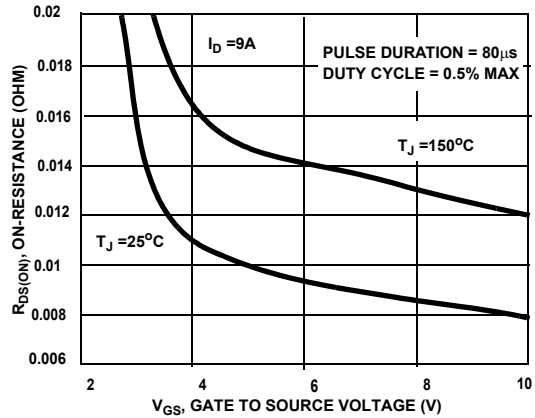


Figure 4. On-Resistance Variation with Gate-to-Source Voltage

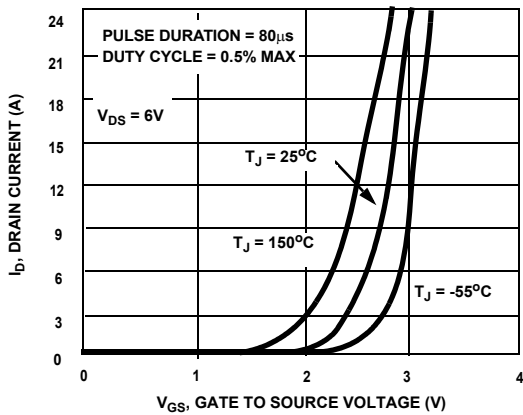


Figure 5. Transfer Characteristics

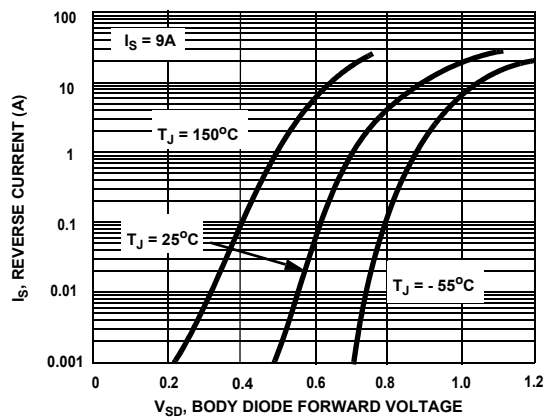


Figure 6. Body Diode Forward Voltage Variation With Source Current and Temperature

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

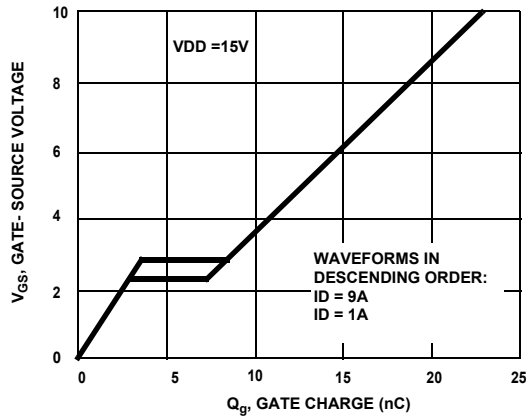


Figure 7. Gate Charge Characteristics

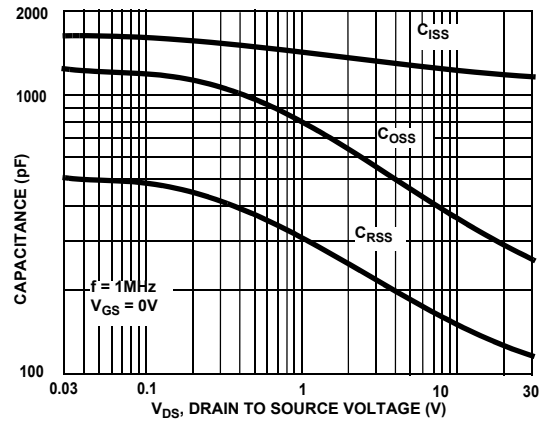


Figure 8. Capacitance Characteristics

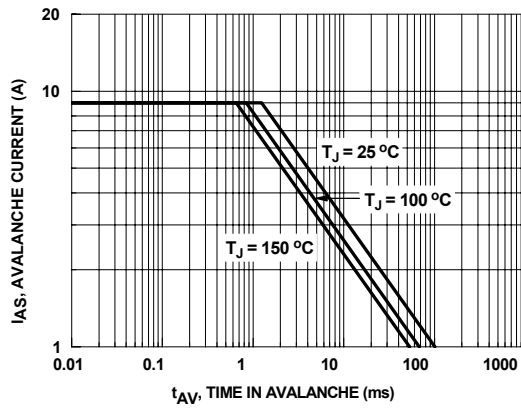


Figure 9. Unclamped Inductive Switching Capability

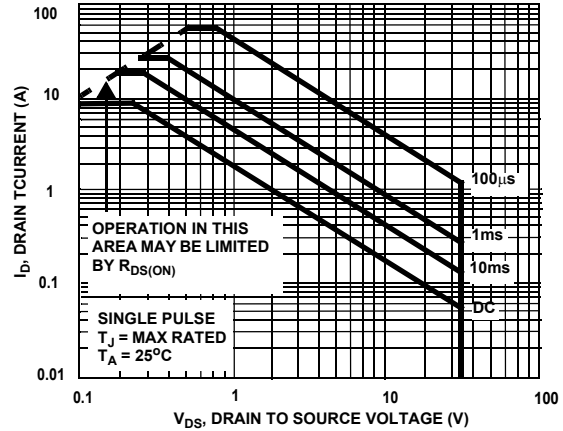


Figure 10. Safe Operating Area

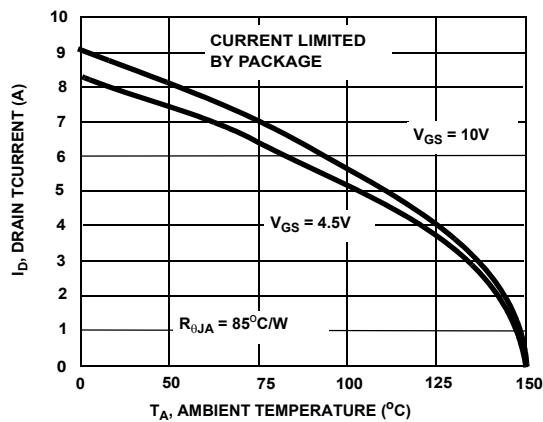


Figure 11. Maximum Continuous Drain Current vs Ambient Temperature

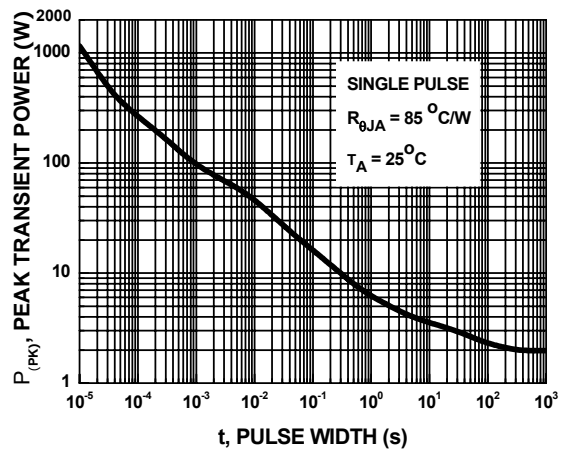


Figure 12. Single Maximum Power Dissipation

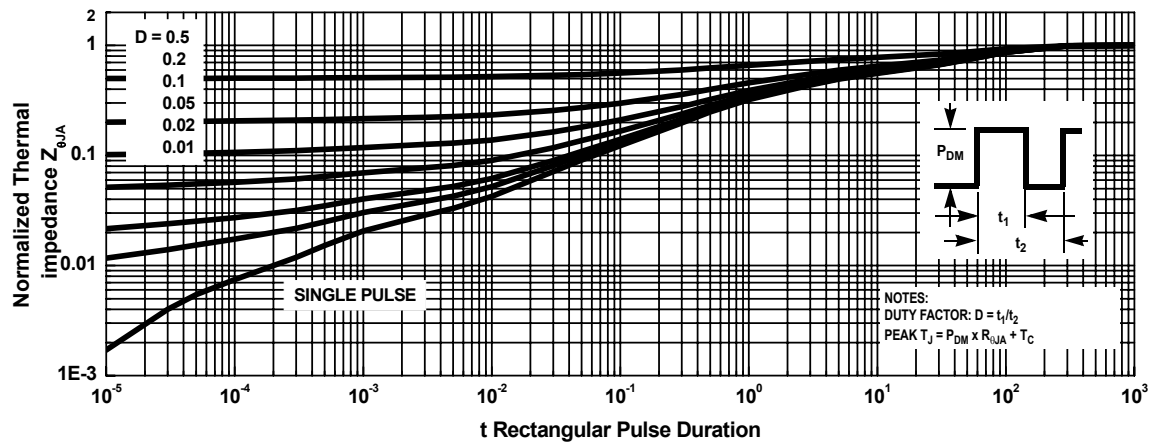


Figure 13. Transient Thermal Response Curve



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No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

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